Photoluminescence of PdS$_2$ and PdSe$_2$ quantum dots†

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Group-10 transition metal dichalcogenide (TMD) materials have recently attracted considerable attention in optoelectronics applications. However, so far their quantum dot (QD) counterparts with photoluminescence (PL) nature still remain to be revealed. In this study, 2 typical types of group-10 TMD material (PdS$_2$ and PdSe$_2$) QDs are fabricated via liquid exfoliation using N-methyl-2-pyrrolidone (NMP) solvent. The absorption and PL spectra of these QD solutions are studied, exhibiting excitation wavelength-dependent behaviors and large Stokes shifts. Furthermore, the quantum yield and decay lifetime are also investigated and analyzed. The obtained results suggest promising optoelectronic applications with group-10 TMD QDs in the future.

1. Introduction

The lack of an intrinsic band gap in graphene has stimulated research into two-dimensional (2D) materials for semiconductor applications.1 Recently, traditional transition-metal dichalcogenide (TMD) semiconductors have become very promising candidates among the 2D materials series owing to the direct band gap behavior in monolayer TMDs at the K point,2 along with excellent electronic, catalytic, optical, and mechanical properties.3–12 Furthermore, TMD materials exhibit superior photoluminescence behavior,13 piezoelectric properties,14–16 and controllable optical performance by modulating valleys in the k space.17–19 The development of several optoelectronic devices, such as strain sensors,19 transistors,20 and highly sensitive and broadband photodetectors21–23 will highly benefit from the assistance of these inherent properties.

The research frontiers in TMDs are mainly focused on investigating novel semiconductor characteristics by combining various transition metal atoms with chalcogens (S, Se, and Te).2 Several noble metal atoms, such as platinum (Pt) and palladium (Pd) can bond to these four chalcogens, resulting in layer structure. In the material’s atomic structure of such TMDs, each unit cell consists of a noble metal atom sandwiched by 2 chalcogen atoms, leading to the formation of a hexagonally plain structure.24–29 Unlike to the traditional TMDs materials these advanced TMDs materials again exhibit several unique material properties, such as superconductivity, high carrier mobility, broad tunable band gap, and stability in the air.26,28–31 The application of such materials in optoelectronic devices is also wide with remarkable performances. For instance, PtS$_2$ with (0.25 (bulk) to 1.6 eV (monolayer)) indirect band gap18,29 has been applied in field-effect transistor (FET),29 Q-switched laser,30 and catalysis.31 PtSe$_2$, with a tunable indirect band gap from 0 (bulk) to 1.2 eV (monolayer), has also been used in saturable absorber32 and broadband photodetectors.33 Then electronic, optical, and catalytic properties with bandgap tunability have also been studied in PdS$_2$ under tensile strain, exhibiting semi-metallic characteristic even for the bilayer structure.34 Furthermore, the indirect band gap with 1.0 eV is found to appear in PdS$_2$ when it reaches monolayer thickness, whereas the metallic characteristics are exhibited for its bulk counterpart.35 A PdS$_2$ logical junction has also recently been reported with 2.5 nm channel length and a gate voltage dependent I–V characteristic.36 Additionally, indirect bandgap PdSe$_2$ with a bandgap of 1.31 eV has been exhibited for its monolayer structure and metallic for the bulk counterpart.36 The applications of PdSe$_2$ based thermal electricity,36 FET,36 and photodetector36 suggest its exceptional optoelectronics properties. In the beginning, the PtS$_2$ was anticipated and experimentally demonstrated as that the photoluminescence (PL) signal is “too weak to be detected” owing to its indirect bandgap, even for the case of its monolayer structure.38 Nonetheless, the PL behavior of PtS$_2$ has successfully observed via scaling down to quantum dots (QDs).41 However, the PL behaviors of PdS$_2$ and PdSe$_2$ are still remained obscure. Since PdS$_2$ and PdSe$_2$ exhibit similar crystal structure with PtS$_2$, including the indirect bandgap, such group-10 TMDs materials arouse our interest for the investigation of PL performance.

QDs are defined when materials reach a size smaller than twice of their excitonic Bohr radius. QDs have been reported as
a novel structure with exceptional large transition energy in comparison to their bulk or layer counterpart, resulting in enhanced PL performance of the materials; thanks to quantum confinement effect.\textsuperscript{42-44} In a previous study, we successfully fabricated PtS\textsubscript{2} QDs \emph{via} low cost liquid exfoliation with water.\textsuperscript{41} Herein, 2 typical group-10 TMDs materials, PdS\textsubscript{2} and PdSe\textsubscript{2}, QDs are fabricated with the aid of similar liquid exfoliation technique, while N-methyl-2-pyrrolidone (NMP) is selected as solvent for its better compatibility of surface energy as compared to the water. PtS\textsubscript{2} QDs solution is also fabricated with same method in order to assist analyzation by comparing with PdS\textsubscript{2} and PdSe\textsubscript{2} QDs. To our knowledge, this is the first experimental demonstration of optical characteristics of PdS\textsubscript{2} and PdSe\textsubscript{2} QDs, where the UV-Vis spectra, PL spectra and the decay lifetimes of PtS\textsubscript{2} QDs, PdS\textsubscript{2} QDs, and PdSe\textsubscript{2} QDs are monitored and analyzed by comparing with each other.

2. Experimental section

2.1 Materials fabrication

In this study, PdS\textsubscript{2}, PdSe\textsubscript{2}, and PtS\textsubscript{2} QDs were fabricated \emph{via} liquid exfoliation from their bulk powder raw materials. NMP was selected to be the solvent for its compatible surface energy, resulting in stabilizing and preventing TMDs nanoparticles from agglomeration. In the first step of the fabrication process, a 50 mg of PtS\textsubscript{2} raw material (Alfa Aescar) was poured into 250 mL of NMP solution. Next, a probe sonication was applied to the mixture under 230 W power with 20 kHz frequency for about 3 hours, while 27 °C temperature was maintained throughout the process. In this case, the operation time of ultrasonic probe was set to 2 s at an interval of 4 s. Then, 2/3 of dispersion close to the liquid level was taken and stirred for 6 h under 140 °C. The supernatant liquor was obtained by centrifugation at 2000 rpm for 5 min to separate QDs from bulky raw materials. This QDs as-prepared solution was taken for the experiments and characterizations.

2.2 Characterization

The high-resolution images and lattice fringes of as-prepared QDs were observed \emph{via} Transmission Electron Microscopy (TEM, Jeol JEM-2100F). The thickness of QDs was scanned under tapping mode with the aid of Atomic Force Microscopy (AFM, Bruker Nanoscope 8). Each of the AFM samples for QDs were prepared \emph{via} drop casting the as-prepared QDs solution on the surface of quartz substrate followed by drying under 80 °C in the air atmosphere. Element contained in as-prepared solution is confirmed by the Energy Dispersive X-ray Spectroscopy (EDX, ULTIM MAX 170) performed on Scanning Electron Microscopy (SEM, GeminiSEM 300). The samples for EDX and SEM measurements are fabricated by drop-casting on the silicon substrate following by drying under the air atmosphere. Chemical composition of raw materials was detected by X-ray photoelectron spectroscopy (XPS, ESCALAB 250Xi, Thermo Fisher Scientific) with achromatic 200 W Al Kz as the X-ray source and the resolution of 0.10 eV. Before conducting the XPS measurement, the powders of raw materials were utilized to eliminate water in the oven under 60 °C for 3 h. The PL measurement was performed with Edinburgh CD920. The emission spectra of QDs solution were monitored on excitation at given wavelength under ambient environment. The excitation source was Xenon lamp. Time-resolved measurements were monitored by HORIBA FluoroMax-4 spectrometer for ultrafast studies and time-correlated single-photon counting (TCSPC) accessory for lifetime determinations. UV-Vis absorption spectroscopy was recorded by Shimadzu UV-2550.

3. Results and discussion

Fig. 1 is an illustration of TEM images for PdS\textsubscript{2}, and PdSe\textsubscript{2}, group-10 TMDs materials QDs. The TEM samples were prepared by drop-casting as-prepared QDs suspensions on holey copper grid, followed by a drying process in the ambient environment under 60 °C for 1 h. The morphologies and scattered distributions of PdS\textsubscript{2}, PdSe\textsubscript{2}, and PtS\textsubscript{2} QDs can be clearly observed from Fig. 1e and f, respectively. The statics of the corresponding size distributions are depicted in Fig. 1c and d, and S1b\textsuperscript{†} for number of 104 PdS\textsubscript{2}, 106 PdSe\textsubscript{2} QDs, and 143 PtS\textsubscript{2} respectively, pronouncing a statistical estimation of their average diameters of 4.99, 4.17, and 4.73 nm. High resolution images of PdS\textsubscript{2}, PdSe\textsubscript{2}, and PtS\textsubscript{2} QDs were captured in Fig. 1e and d, and S1b\textsuperscript{†} respectively, indicating the high crystallinity of the as-prepared samples. For the PdS\textsubscript{2} QDs with a determined lattice distance of 0.27 nm is corresponding to the (200) plane, which agrees well with a simulated data as recently reported in the literature.\textsuperscript{29} Then the PdSe\textsubscript{2} QDs shows a 0.27 nm lattice periodicity that matches its (200) crystalline plane.\textsuperscript{25} The interplanar spacing of 0.29 nm for PtS\textsubscript{2} QDs as observed in Fig. S1b\textsuperscript{†} is corresponding to (100) plane.\textsuperscript{26,28,41} The results imply that the ultrasonic energy is sufficient to separate layered group-10 TMDs materials from the van der Waals forces and even splits them into nanoscales. Thanks to the outstanding stability of group-10 TMDs materials, which allows to obtain good crystallinity in the materials.

Further investigation on QDs’ height profiles and height distributions were conducted \emph{via} AFM measurement as shown in Fig. 2. The QDs were scattered on the quartz substrates by scanning processes. The scan size was set to be 1 × 1 μm\textsuperscript{2} and the observation of QDs was taken place randomly on the substrates. The height variation of PdS\textsubscript{2}, PdSe\textsubscript{2}, and PtS\textsubscript{2} QDs can be clearly distinguished along line profiles as depicted in Fig. 2a and b, S2a,\textsuperscript{†} respectively. The statics of 54 PdS\textsubscript{2} QDs are shown in Fig. 2c, indicating an average height of 2.61 nm, which can be considered as 6 to 7 layers.\textsuperscript{27} The height information of 25 observed PdSe\textsubscript{2} QDs is recorded in Fig. 2d. The thickness of such QDs are assumed to be 4 to 5 layers referring to 1.99 nm average height.\textsuperscript{27} The average height of 38 PtS\textsubscript{2} QDs is determined to be 2.82 nm, suggesting 5 to 6 layers’ thickness,\textsuperscript{28} and their height distribution is depicted in Fig. S2b.\textsuperscript{†}

The element compositions of as-prepared QDs solutions are detected \emph{via} the Scanning Electron Microscopy (SEM) and the Energy Dispersive X-ray Spectroscopy (EDX) mapping. The mapping analysis shown in Fig. 3a–c confirms the existence of Pd and S elements in PdS\textsubscript{2} QDs solution. The consistent
The EDX is not suitable used as quantitative analysis method. Therefore, the XPS measurement was conducted on the raw powder materials counterparts in order to investigate their chemical compositions as shown in Fig. 4. For Pt4f spectra of PtS2, deconvolution of the line shape reveals two doublets, Pt2+ and Pt4+, essential to reconstruct Pt signals, as shown in Fig. S4a.† Pt2+ with level positions of Pt4f7/2 and Pt4f5/2 are fitted at 71.98 eV and 75.38 eV, along with Pt4+4f7/2 and Pt4+4f5/2 fitted at 71.98 eV and 75.38 eV, respectively. S2p deconvolution as shown in Fig. S4b† can be conducted showing one doublets: S2p3/2 at 162.78 eV and S2p1/2 at 164.18 eV. The signal with 168.08 eV binding energy refers to sulphate series constituting HSO4− or SO42−. Such considerable intensity of sulphate signal indicates partial oxidation on the surface of the PtS2 raw materials, resulting in Pt2+ as predominant doublet. The atomic percentage of Pt and S is determined to be 17.79% and 27.97%. The stoichiometric ratio is obtained as less than 0.5, which may be due to the origination of sulphate series from surface oxidation during drying process. For PdS2, signals of Pd3d5/2 and Pd3d3/2 are shown in Fig. 3d with binding energies of 336.18 eV and 341.48 eV. The S2p spectra for PdS2 can be divided into two chemical states as shown in Fig. 4b. For the case of PtS2 raw materials, S(0)2p3/2 and S(0)2p1/2 are simulated at 161.08 eV and 163.38 eV, while S(II)2p3/2 and S(II)2p1/2 with 162.28 eV and 164.38 eV exhibit similar to the S2p spectra. PdS2 stored under ambient conditions with no detectable sulphate series signal implies its high stability. The atomic percentage of Pd and S are found to be 3.08% and 6.96% on the surface, exhibiting a stoichiometric ratio very close to 1/2 due to probably the absence of oxidation. The level positions of Pd3d5/2 and Pd3d3/2 in PdS2 with 336.18 eV and 341.48 eV as depicted in Fig. 4c agree well with the presence of Pd signals in PdS2. The deconvolution of Se element gives rising to Se3d5/2 signal at 54.18 eV and Se3d3/2 signal at 54.98 eV as shown in Fig. 4d. The atomic percentage of 6.76% and 15.11% for the Pd and Se elements support the idea of air stability as recently reported in the literature.26

The PL emission spectra of PdS2, and PdSe2 QDs show excitation wavelength-dependent behaviors, i.e. the wavelength of PL emission peak red-shifts under crescent excitation.
wavelength, which have been widely reported by several studies on semiconductor QDs,\textsuperscript{47,48} traditional TMDs QDs,\textsuperscript{42,44} and carbon QDs.\textsuperscript{49,50} Due to quantum size effect, the poly-diversity of QDs sizes give rise to the variation of band gap energies. The larger QDs exhibit lower band gap energies, and vice versa. The PL spectra of PdS\textsubscript{2} QDs as shown in Fig. 5a were observed from 400 nm to 567 nm under the excitation ranging from 320 nm to 480 nm. The highest PL peak is determined to be 491 nm for the

Fig. 2  Line profiles and corresponding AFM images of (a) PdS\textsubscript{2} QDs, and (b) PdSe\textsubscript{2} QDs; height distributions based on several images of (c) PdS\textsubscript{2} QDs, and (d) PdSe\textsubscript{2} QDs.

Fig. 3  (a) SEM image of PdS\textsubscript{2} QDs solution drop-casting on silicon substrate; (b and c) EDX elemental maps of Pd and S elements in (a); (d) SEM image of PdSe\textsubscript{2} QDs solution drop-casting on silicon substrate; (e and f) EDX elemental maps of Pd and Se elements in (d).
excitation wavelength of 400 nm. The PL spectra of PdSe₂ are depicted in Fig. 5b, displaying emission peaks ranging 379 nm to 551 nm, while the excitation wavelength was being tuned from 300 nm to 480 nm. The 340 nm excitation wavelength presents a maximum emission peak at 413 nm. The PtS₂ QDs sample exhibits PL peak wavelength ranging from 381.5 to 548 nm while excitation wavelength shifts from 300 nm to 480 nm as shown in Fig. S5.† The maximum emission peak could be found at 468.5 nm for the excitation wavelength of 380 nm. The maximum emission peak wavelengths demonstrate a trend of PdSe₂ QDs < PdS₂ QDs, which might be owing to including but not limited to their intrinsic chemical property. The intrinsic bandgaps may also play important role in defining the emission peak wavelength. Since monolayer PdS₂ holds a smaller bandgap than monolayer PdSe₂, the PdS₂ sample exhibits a substantial redshift vs. PdSe₂ sample. This PL emission peak trend also accords with their average sizes determined via TEM characterizations, which may further prove the quantum size effect.

The absorption spectra are depicted in Fig. 6 with black lines. The distinct absorption peaks at 330, 274, and 307 nm can be observed in Fig. 6a and Sb, and S5† for the solutions of PdS₂, and PdSe₂, and PtS₂ QDs, respectively. The maximum emission peaks (in blue lines) for all QDs samples and their corresponding photoluminescence excitation (PLE) spectra (in red line) are also displayed in Fig. 6. The maximum PLE peaks for PdS₂, and PdSe₂, and PtS₂ QDs samples exhibit at 397.5, 346, and 377 nm as shown in Fig. 6a and b, and S6,† respectively. These PLE peaks agree well with the previous PL emission analysis, implying to 0.59 eV, 0.58 eV, and 0.64 eV stokes shifts for the PdS₂, PdSe₂, and PtS₂, respectively. Such large stokes shifts are caused by the quantum confinement effect when materials size approaches to the atomic scale, resulting in dramatic expansion of spatial overlaps for electron–hole wave functions.51 The splitting of the lowest singlet fine structure states and highest triplet states grows much larger comparing to their layers or bulky structure.51,52 The dark exciton ensues when excitation experiences a rapid thermalization process from active singlet state to passive triplet state, leading to red shift of PL emission spectrum and larger stokes shift. Quantum yield (QY) of PdS₂, PdSe₂, and PtS₂ QDs are evaluated to be 11.11%, 7.18%, and 14.42%, respectively and tabulated in Table 1. The PL QY for as-prepared QDs samples are calculated by eqn (1).

\[
QY = \frac{\eta^2}{\eta_{ref}^2} \frac{A_{ref}}{A} \frac{F}{F_{ref}} \cdot QY_{ref}
\]

Fig. 4 High resolution X-ray photoelectron spectra of PdS₂ for (a) Pd3d region and (b) S2p region; PdSe₂ for (c) Pd3d region and (d) Se3d region.

Fig. 5 Emission (Em) spectra of (a) PdS₂ QDs solution, and (b) PdSe₂ QDs solution.
where, $\eta$ represents the refractive index of the solvent. The quinine sulfate is dissolved in H$_2$SO$_4$ to prepare reference solution by controlling its absorbance similar to the as-prepared PdS$_2$, PdSe$_2$, and PtS$_2$ solutions. Quinine sulfate solution holds refractive index of 1.33, while the QDs is dissolved in NMP solution which holds a refractive index of 1.47.

$F$ and $A$ are referring to the integrated emission intensity and absorbance, respectively for samples and reference compound. In the next step, the time-resolved PL decay measurement is performed at room temperature as depicted in Fig. 7, while PdS$_2$, PdSe$_2$, and PtS$_2$ QDs samples are excited by 377, 397.5, and 346 nm wavelengths, respectively. The decay lifetime curves of QDs samples are monitored and fitted by dual-exponential function. The function presented in eqn (2) explains that the decay curve is dominated by two de-excitation processes in the surface states and the core states, corresponding to a long-lived component $s_1$ and a short-lived component $s_2$.

$$A(t) = a_1 \exp \left(-t/\tau_1\right) + a_2 \exp \left(-t/\tau_2\right)$$

where $\tau_1$ and $\tau_2$ are the decay lifetimes corresponding to components $s_1$ and $s_2$, respectively.

$$\tau_{\text{ave}} = \frac{a_1 \tau_1^2 + a_2 \tau_2^2}{a_1 \tau_1 + a_2 \tau_2}$$

Table 1: Quantum yields of PtS$_2$ QDs, PdS$_2$ QDs, and PdSe$_2$ QDs solutions

<table>
<thead>
<tr>
<th></th>
<th>$A$</th>
<th>$F$</th>
<th>$\eta$</th>
<th>QY</th>
</tr>
</thead>
<tbody>
<tr>
<td>Quinine sulfate</td>
<td>0.024</td>
<td>6 095 040</td>
<td>1.33</td>
<td>54%</td>
</tr>
<tr>
<td>PtS$_2$ QDs</td>
<td>0.036</td>
<td>1 459 610</td>
<td>1.47</td>
<td>14.42%</td>
</tr>
<tr>
<td>PdS$_2$ QDs</td>
<td>0.027</td>
<td>850 509</td>
<td>1.47</td>
<td>11.11%</td>
</tr>
<tr>
<td>PdSe$_2$ QDs</td>
<td>0.034</td>
<td>619 276</td>
<td>1.47</td>
<td>7.18%</td>
</tr>
</tbody>
</table>

Table 2: Fitted decay lifetimes for PtS$_2$ QDs, PdS$_2$ QDs, and PdSe$_2$ QDs solutions

<table>
<thead>
<tr>
<th></th>
<th>$\tau_1$/ns</th>
<th>$\tau_2$/ns</th>
<th>$\tau_{\text{ave}}$/ns</th>
</tr>
</thead>
<tbody>
<tr>
<td>PtS$_2$ QDs</td>
<td>$8.85 \times 10^8$</td>
<td>1.5</td>
<td>1.69</td>
</tr>
<tr>
<td>PdS$_2$ QDs</td>
<td>25 672</td>
<td>9.06</td>
<td>2.63</td>
</tr>
<tr>
<td>PdSe$_2$ QDs</td>
<td>$6.33 \times 10^7$</td>
<td>3.64</td>
<td>2.37</td>
</tr>
</tbody>
</table>

Fig. 6 Normalized absorption spectra (black curve) for (a) PdS$_2$ QDs and (b) PdSe$_2$ QDs solutions. Photoluminescence excitation (PLE) spectra (red curve) for (a) 491 and (b) 413 nm emission wavelengths, which are observed at the peaks of the corresponding emission spectra (blue curve).

Fig. 7 Decay profile of PdS$_2$ QDs, PdSe$_2$ QDs, and PtS$_2$ QDs solutions.

4. Conclusions

In this study, 2 typical group-10 TMDs materials QDs were fabricated via solvent exfoliation and investigated by comparing with a different group-10 TMDs PtS$_2$ QDs. The as-prepared PdS$_2$ and PdSe$_2$ QDs exhibit average diameters of 4.99 and 4.17 nm, while their average thicknesses were determined as 2.61 and 1.99 nm. Very good air stabilities were observed for PdS$_2$ and PdSe$_2$. The optical characteristics for those QDs solutions were monitored, exhibiting excitation wavelength-dependent
behavior and large stokes shifts. The PL emission wavelengths might be strongly related to the size of QDs due to quantum size effect. This study is basically a short demonstration of simple synthesis process using solvent exfoliation and several optical performance parameters for two different group-10 TMDs materials of PbS and PbSe QDs. Most importantly, to our knowledge, so far this is the first demonstration of PL behaviors for PbS and PbSe QDs. We believe that this study with some excellent optical properties of these noble 2D materials should be beneficial for applications related to real time imaging, single molecule detection, light-emitting diode, and biosensing in addressing some analytical and biological issues which are currently being encountered in the fields.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

This work is financially supported by the Science and Technology Innovation Commission of Shenzhen (JCYJ20180306173805740 and JCYJ20170303160136888).

Notes and references